

# SOT-227 Power Module Single Switch - Power MOSFET, 420 A



PRIMARY CHARACTERISTICS					
$V_{DSS}$	100 V				
R <sub>DS(on)</sub>	0.0013 Ω				
I <sub>D</sub> <sup>(1)</sup>	330 A at 90 °C				
Туре	Modules - MOSFET				
Package	SOT-227				

#### **FEATURES**

- $I_D > 420 \text{ A}, T_C = 25 \, ^{\circ}\text{C}$
- TrenchFET® power MOSFET
- Low input capacitance (Ciss)
- · Reduced switching and conduction losses
- Ultra low gate charge (Q<sub>q</sub>)
- Avalanche energy rated (U<sub>IS</sub>)
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

2500

-55 to +175

٧

°C

ABSOLUTE MAXIMUM RAT	'INGS ( $T_C$	= 25 °C unless otherwise specified)		
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
MOSFET				•
Drain to source voltage	$V_{DSS}$		100	V
Ocalia a salada a salada V	1 (1)	T <sub>C</sub> = 25 °C	435	A
Continuous drain current, V <sub>GS</sub> at 10 V	I <sub>D</sub> <sup>(1)</sup>	T <sub>C</sub> = 90 °C	330	
Pulsed drain current	I <sub>DM</sub> <sup>(2)</sup>		1130	
Power dissipation	$P_{D}$	T <sub>C</sub> = 25 °C	652	W
Gate to source voltage	V <sub>GS</sub>		± 20	V
Single pulse avalanche energy	E <sub>AS</sub>	$T_{C}$ = 25 °C, L = 10 mH, $V_{GS}$ = 10 V	11.5	J
Single pulse avalanche current	I <sub>AS</sub>	$T_C = 25  ^{\circ}\text{C},  L = 10  \text{mH},  V_{GS} = 10  \text{V}$	48	Α

any terminal to case, t = 1 min

#### Notes

VISOL

 $T_{J}$ 

Operating junction temperature range

Insulation voltage (RMS)

<sup>(1)</sup> Maximum continuous current admitted 100 A to do not overcome the maximum temperature of terminals

<sup>(2)</sup> Limited at maximum junction temperature



THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction and storage tem	perature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	=.	175	°C
Junction to case	MOSFET	$R_{thJC}$		-	-	0.23	°C/W
Case to heat sink	Module	R <sub>thCS</sub>	Flat, greased surface	-	0.1	-	C/VV
Weight				-	30	-	g
Mounting torque			Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)
Mounting torque			Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT-227			

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 750 \mu\text{A}$	100	-	-	V
Static drain to source on-resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 200 A	-	1.3	2.15	mΩ
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 750 \mu A$	2.2	2.9	3.8	V
Forward transconductance	9 <sub>fs</sub>	$V_{DS} = 20 \text{ V}, I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}$	-	94	-	S
Dusin to source leakens summed	,	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V	-	0.6	4	
Drain to source leakage current	I <sub>DSS</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C	-	32	-	μA
Gate to source leakage	I <sub>GSS</sub>	V <sub>GS</sub> = ± 20 V	-	-	± 350	nA
Total gate charge	Qg	I <sub>D</sub> = 200 A V <sub>DS</sub> = 50 V	-	375	-	
Gate to source charge	Q <sub>gs</sub>		-	84	-	nC
Gate to drain ("Miller") charge	Q <sub>gd</sub>	V <sub>GS</sub> = 10 V		138	-	1
Turn-on delay time	t <sub>d(on)</sub>	V <sub>DD</sub> = 50 V	-	45	-	
Rise time	t <sub>r</sub>	$I_D = 100 \text{ A}$ $R_g = 1.2 \Omega$	-	275	-	
Turn-off delay time	t <sub>d(off)</sub>		-	152	-	ns
Fall time	t <sub>f</sub>	V <sub>GS</sub> = 10 V	-	172	-	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V	-	17.3	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25 V	-	9.2	-	nF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1 MHz	-	0.9	-	

<b>SOURCE-DRAIN RATINGS AND CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Continuous source current (body diode)	I <sub>S</sub>	MOSFET symbol showing the integral	-	-	435	
Pulsed source current (body diode)	I <sub>SM</sub>	reverse p-n junction diode	-	-	1130	A
Diode forward voltage	V <sub>SD</sub>	I <sub>S</sub> = 200 A, V <sub>GS</sub> = 0 V	-	0.91	1.5	V
Reverse recovery time	t <sub>rr</sub>	T 05 00 1 1 50 4	-	171	-	ns
Reverse recovery charge	Q <sub>rr</sub>	$T_J = 25 ^{\circ}\text{C}, I_F = I_S = 50 \text{A},$ $dI/dt = 100 \text{A/}\mu\text{s}, V_B = 50 \text{V}$	-	740	-	nC
Reverse recovery current	I <sub>RM</sub>		-	8.7	-	Α



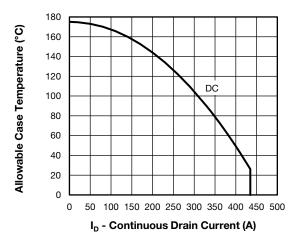


Fig. 1 - Maximum Continuous Drain Current vs. Case Temperature

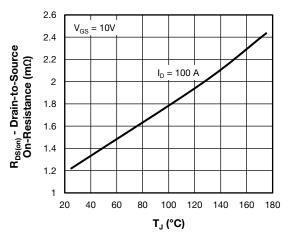


Fig. 4 - Typical Drain-to-Source On-Resistance vs. Temperature

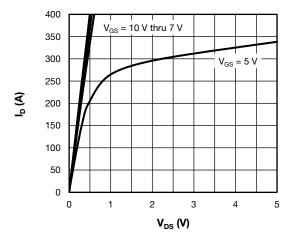


Fig. 2 - Typical Drain to Source Current Output Characteristics at  $T_{J}=25\ ^{\circ}\text{C}$ 

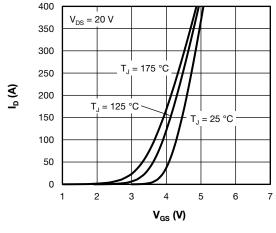


Fig. 5 - Typical Transfer Characteristics

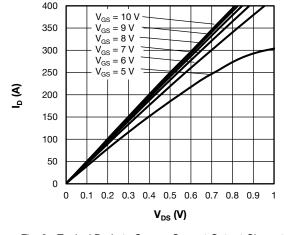


Fig. 3 - Typical Drain to Source Current Output Characteristics at  $T_{J} = 125\ ^{\circ}\text{C}$ 

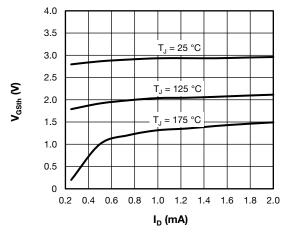


Fig. 6 - Typical Gate Threshold Voltage Characteristics



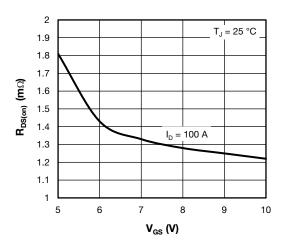


Fig. 7 - Typical Drain-State Resistance vs. Gate-to-Source Voltage

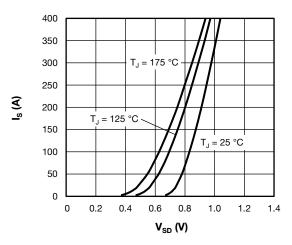


Fig. 8 - Typical Body Diode Source-to-Drain Current Characteristics

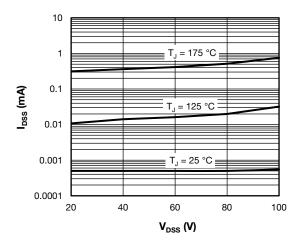


Fig. 9 - Typical Zero Gate Voltage Drain Current

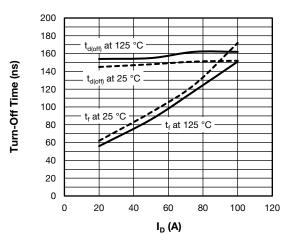


Fig. 10 - Typical Turn off Switching Time vs.  $I_d$   $V_{DD}=50$  V,  $R_g=1.2~\Omega,\,V_{GS}=\pm~10$  V,  $L=500~\mu H$ 

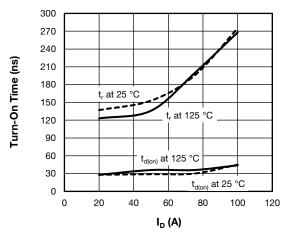


Fig. 11 - Typical Turn-on Switching Time vs. I<sub>d</sub>  $V_{DD}$  = 50 V,  $R_q$  = 1.2  $\Omega$ ,  $V_{GS}$  =  $\pm$  10 V, L = 500  $\mu$ H

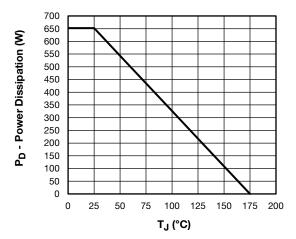


Fig. 12 - Power Dissipation Curve



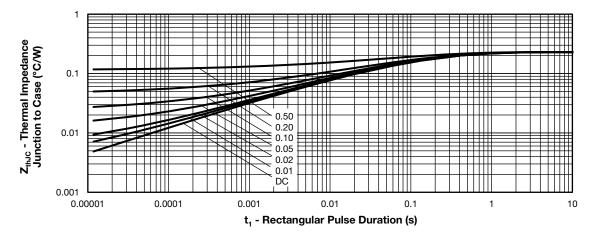


Fig. 13 - Maximum Thermal Impedance Junction-to-Case Characteristics

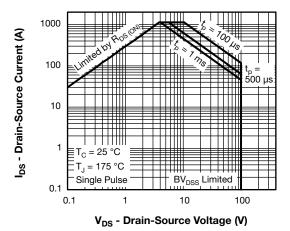
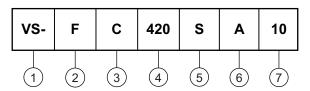


Fig. 14 - Safe Operating Area

#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

2 - MOSFET module

MOSFET die generation

**4** - Current rating (420 = 420 A)

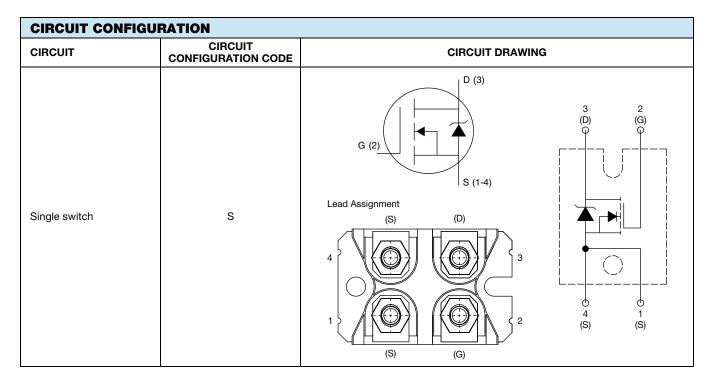
5 - Circuit configuration (S = single switch)

6 - Package indicator (SOT-227 standard insulated base)

7 - Voltage rating (10 = 100 V)

Quantity per tube is 10, M4 screw and washer included



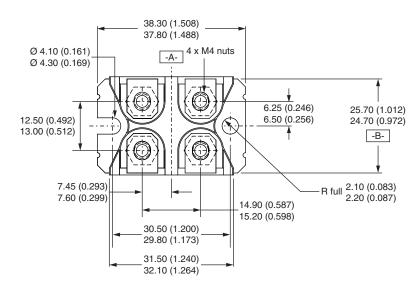


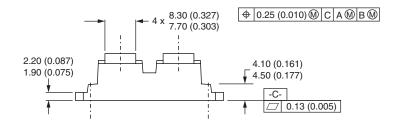
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95423</u>					
Packaging information	www.vishay.com/doc?95425				

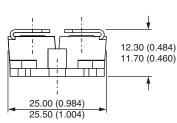


### **SOT-227 Generation II**

#### **DIMENSIONS** in millimeters (inches)







#### Note

• Controlling dimension: millimeter



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